

FAST RECOVERY RECTIFIER

1F1 THRU 1F7 VOLTAGE RANGE CURRENT 50 to 1000 Volts 1.0 Ampere

FEATURES

• Fast switching speed for high efficiency

• Low reverse leakage

• High forward surge current capacity

• High temperature soldering guaranteed: 260 /10 seconds, 0.375" (9.5mm) lead length

MECHANICAL DATA

Case: transfer molded plastic

• Epoxy: UL94V - 0 rate flame retardant

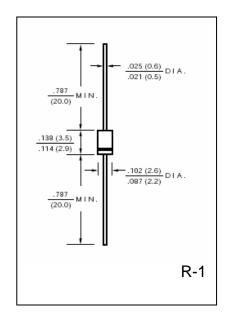
• Polarity: Color band denotes cathode end

• Lead: Plated axial lead, solderable per MIL-STD-202E

method 208C

Mounting position: any

• Weight: 0.007 ounce, 0.20 gram



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

- Ratings at 25°C ambient temperature unless otherwise specified
- Single Phase, half wave, 60Hz, resistive or inductive load
- For capacitive load derate current by 20%

	SYMBOLS	1F1	1F2	1F3	1F4	1F5	1F6	1F7	UNIT
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current, 0.375" (9.5mm) lead length At T _C = 25°C	I _(AV)	1.0							Amps
Peak Forward Surge Current 8.3mS single half sine wave superimposed on rated load (JEDEC method)	I_{FSM}	I_{FSM} 25							
Maximum Instantaneous Forward Voltage @ 1.0A	$V_{\rm F}$	1.3							Volts
Maximum DC Reverse Current at Rated $T_A = 25$ °C DC Blocking Voltage per element $T_A = 100$ °C	I_R	5.0 100							μА
Maximum Reverse Recovery Time Test conditions $I_F = 0.5A$, $I_R = 1.0A$, $I_{RR} = 0.25A$	t _{rr}		150		250	500		nS	
Typical Junction Capacitance (Measured at 1.0MHz and applied reverse voltage of 4.0V)	C_{J}	15							pF
Typical Thermal Resistance (Note 1)	$R_{\theta JA}$	50							^o C/W
Operating Junction Temperature Range	T_{J}	(-65 to +150)							°C
Storage Temperature Range	T_{STG}	(-65 to +150)							°C

Notes:

1. Thermal resistance from junction to ambient with 0.375" (9.5mm) lead length, PCB mounted



RATINGS AND CHARACTERISTIC CURVES 1F1 THRU 1F7

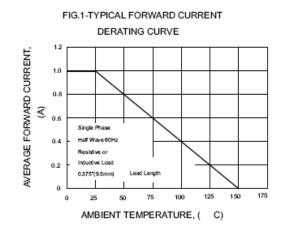


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

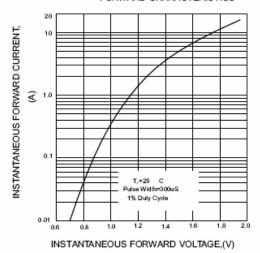


FIG.5-TYPICAL JUNCTION CAPACITANCE

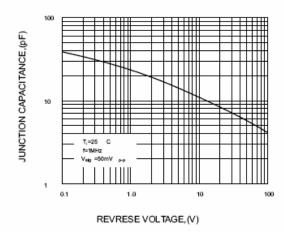


FIG.2-MAXIMUM NON-REPETITIVE PEAK

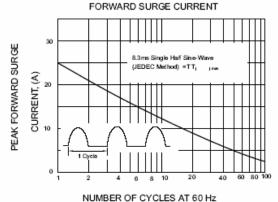


FIG.4-TYPICAL REVERSE

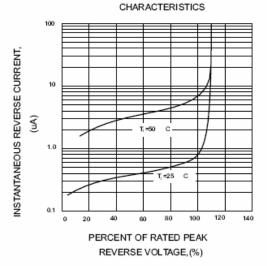
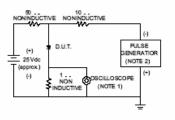


FIG.6-TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1.Rise Time =7ns max. Input Impedance= 1 megohm. 22pF

2.Rise time=10ns max. Source impedance= 50 ohms

